

UNISONIC TECHNOLOGIES CO., LTD

UTG40N120WT

Preliminary

Insulated Gate Bipolar Transistor

1200V, SMPS N-CHANNEL IGBT

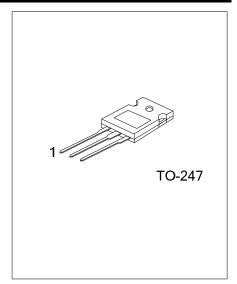
DESCRIPTION

The UTC **UTG40N120WT** is a N-channel IGBT. it uses UTC's advanced technology to provide customers with high input impedance, high switching speed and low conduction loss, etc.

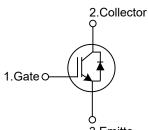
The UTC **UTG40N120WT** is suitable for high voltage switching, high frequency switch mode power supplies.

FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: V_{CE(SAT).Typ.} =1.8V @ I_C=40A, V_{GE}=15V (T_c =25°C)



SYMBOL



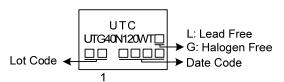
3.Emitte

ORDERING INFORMATION

Ordering	Deekere	Pin Assignment			Deeking		
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG40N120WTL-T47-T	JTG40N120WTL-T47-T UTG40N120WTG-T47-T		G	С	Е	Tube	
Note: Pin Assignment: G: Gate C: Collector E: Emitter							
UTG40N120WTG-T47-T	(1) T: Tube						

		(2)Package Type	(2) T47: TO-247
		(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



ABSOLUTE MAXIMUM RATINGS (TA=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	V	
Gate-Emitter Voltage		V _{GES}	±20	V	
Transient Gate-emitter voltage (<i>t</i> p <	5 ms)		±25	V	
	T _c =25°C		80	А	
Continuous Collector Current	T _c =100°C	lc	40	А	
Collector Current Pulsed (Note 1)		I _{CM}	160	А	
Diada Famurad Oursent	T _c =25°C	l _F	80	А	
Diode Forward Current	T _c =100°C		40	А	
Short Circuit Withstand Time					
$V_{\rm GE}$ = 15V, $V_{\rm CC} \le 200$ V					
Allowed number of short circuits < 1000		tsc	5	μs	
Time between short circuits: \geq 1.0s					
$T_{\rm VJ}$ = 25°C					
Power Dissipation (T _C =25°C)		PD	285	W	
Operating Junction Temperature		TJ	-40 ~ +175	°C	
Storage Temperature Range		T _{STG}	-55 ~ +175	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged. 2. Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θις	0.44	°C/W



■ ELECTRICAL CHARACTERISTICS (Tc=25°C, unless otherwise noted)

PARAMETER	ETER SYMBOL TEST CONDITIONS			MIN	TYP	MAX	UNIT		
Off Characteristics									
Collector-Emitter Breakdown Voltage	BV _{CES}	3		1200			V		
Collector Cut-Off Current	ICES	V _{CE} =1200V, V _{GE} =0V				5	μA		
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V				±400	nA		
On Characteristics									
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250µA, V _{CE} =V _{GE}	c=250µA, V _{CE} =V _{GE}			7.5	V		
	N (I _C =40A, V _{GE} =15V	T _C =25°C		1.8	2.3	V		
Collector to Emitter Saturation Voltage	V _{CE(SAT)}		T _C =125°C		2.2		V		
Dynamic Characteristics					_				
Input Capacitance	CIES			3490		рF			
Output Capacitance	COES	V _{CE} =25V, V _{GE} =0V, f=1		129		рF			
Reverse Transfer Capacitance	CRES			32.5		рF			
Switching Characteristics		_							
Total Gate Charge	Q_G			152.4		nC			
Gate-Emitter Charge	Q_GE	V _{CE} =600V, I _C =40A, V _{GE} =15V			36.6		nC		
Gate-Collector Charge	Q _{GC}				70.8		nC		
Turn-On Delay Time	t _{DON)}	V _{cc} =600V, I _c =40A, R _G =5Ω, V _{GE} =0~15V, L=500μH			20		ns		
Rise Time	t _R				42.4		ns		
Turn-Off Delay Time	tdoff)				122		ns		
Fall Time	t _F				254		ns		
Turn-On Switching Loss	Eon				3.186		mJ		
Turn-Off Switching Loss	EOFF			3.02		mJ			
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS									
Forward Voltage Drop	VF	I _F =40A				2.5	V		
Reverse Recovery Time	t _{rr}	I _F =40A, dI/dt=100A/µS, V _{CC} =400V			68.2		ns		
Reverse Recovery Charge	Qrr				2.74		μC		
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UTG40N120WT

TEST CIRCUIT AND WAVEFORMS

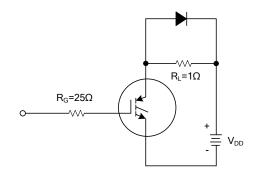


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

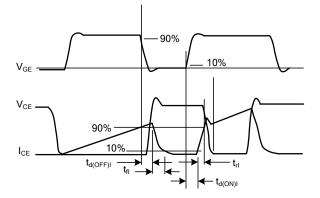


Fig 2. SWITCHING TEST WAVEFORMS

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